

UNITED STATES PATENT AND TRADEMARK OFFICE  
CERTIFICATE OF CORRECTION

PATENT NO. : 6,975,552 B2  
APPLICATION NO. : 10/644610  
DATED : December 13, 2005  
INVENTOR(S) : Tae H. Kim

Page 1 of 3

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

<u>Column, Line</u>	<u>Reads</u>	<u>Should Read</u>
Item (57), Line 3	"and an open digit line"	--and open digit line--
Column 1, Lines 45, 50 and 52	"complimentary"	--complementary--
Column 2, Line 40	"pair is surrounded"	--pair being surrounded--
Column 4, Line 30	"to which portion of a digit line memory cells are"	--to which portions of a digit line of memory cells are--
Column 4, Line 41	"aspects of a open digit line"	--aspects of an open digit line--
Column 4, Line 64	"array 10, thus, coupling"	--array 10, thus coupling--
Column 5, Line 57	"memory arrays, thus,"	--memory arrays, thus--
Column 5, Line 59	"to active column 50, 80"	--to active columns 50, 80--
Column 6, Line 27	"but are instead, shifted"	--but are instead shifted--
Column 6, Line 41	"are desired. For example,"	--are desired; for example,--

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Column 6, Line 66	"MDL portion <b>156</b> .	--MDL portion <b>156</b> .
	virtue of the data state	Consequently, the voltage
	stored by the"	of the digit line will be
		altered from the precharge
		voltage by virtue of the
		data state stored by the--
Column 7, Line 38	"of the memory arrays	--of the memory arrays <b>202a</b> ,
	<b>202a, 202b</b> is a respective	<b>202b</b> is a respective
	row various"	row address latch <b>226</b> ,
		which stores the row
		address, and a row decoder
		<b>228</b> which applies various--

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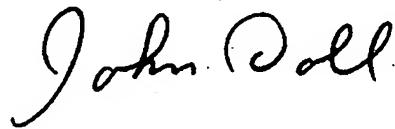
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It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 14, Line 21      "cells of the column"      --cells of the column--

This certificate supersedes the Certificate of Correction issued December 25, 2007.

Signed and Sealed this  
Seventeenth Day of February, 2009



JOHN DOLL  
*Acting Director of the United States Patent and Trademark Office*